

FEATURES

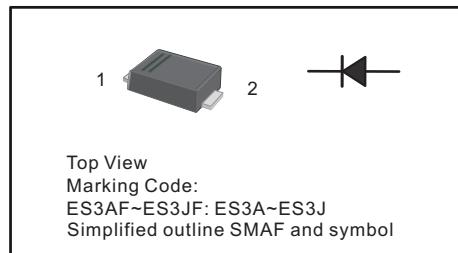
- ◆ For surface mount applications
- ◆ Glass passivated chip junction
- ◆ Low profile package
- ◆ Superfast reverse recovery time
- ◆ Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ◆ Case: SMAF molded plastic body
- ◆ Terminals: Solderable per MIL-STD- 750, Method 2026
- ◆ Weight: Approximated 0.027 grams

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



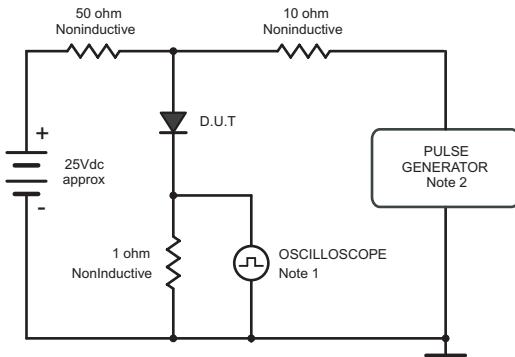
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	ES3AF -TN	ES3BF -TN	ES3CF -TN	ES3DF -TN	ES3EF -TN	ES3GF -TN	ES3JF -TN	UNIT
T _{st} [°C] at 25°C junction temperature	X _{ÜUT} A	I _Ü A	F _{ÜÜ} A	F _Ü A	G _{ÜÜ} A	H _{ÜÜ} A	I _{ÜÜ} A	I _{ÜÜ} A	X _A
T _{st} [°C] at 100°C junction temperature	X _{ÜT} U _A	H _Ü A	I _Ü A	F _Ü A	F _Ü A	G _Ü A	G _Ü A	I _Ü A	X _A
T _{st} [°C] at 150°C junction temperature	X _{ÜÜ} O	I _Ü A	F _{ÜÜ} A	F _Ü A	G _{ÜÜ} A	H _{ÜÜ} A	I _{ÜÜ} A	I _{ÜÜ} A	X _A
T _{st} [°C] at 175°C junction temperature	Q _{ÜÜ} D					H _{ÜÜ} A			°C _A
U _{SD} [V] at 100°C junction temperature	Q _{ÜÜ} A					F _{ÜÜ} A			°C _A
T _{st} [°C] at 100°C junction temperature	X _Ü A		F _Ü A		F _Ü A		F _Ü A		X _A
T _{st} [°C] at 150°C junction temperature	Q _Ü A					I _Ü A			°C _A
V _R [V] at 100°C junction temperature	Ü _R					I _Ü] _Ø
T _{st} [°C] at 100°C junction temperature	V _{ÜÜ} A					I _{ÜÜ} A] _Ü A
V _R [V] at 100°C junction temperature	Ü _R _Ü A					I _Ü A			°C _Ü A
U _{SD} [V] at 100°C junction temperature	V _{ÜÜ} Ü _Ü A					E _Ü A	E _Ü A		°C _A

Notes:
1. All ratings are based on the following conditions:
2. Junction temperature = 25°C
3. Ambient temperature = 25°C
4. Maximum junction temperature = 150°C
5. Maximum ambient temperature = 70°C
6. Maximum operating junction temperature = 100°C
7. Maximum operating ambient temperature = 50°C
8. Maximum reverse voltage = 100V
9. Maximum forward current = 1A
10. Maximum reverse current = 100mA
11. Maximum power dissipation = 0.027W
12. Maximum reverse recovery time = 10ns
13. Maximum forward recovery time = 10ns
14. Maximum forward voltage drop = 0.6V
15. Maximum reverse leakage current = 100nA
16. Maximum forward current = 1A
17. Maximum reverse current = 100mA
18. Maximum power dissipation = 0.027W
19. Maximum reverse recovery time = 10ns
20. Maximum forward recovery time = 10ns
21. Maximum forward voltage drop = 0.6V
22. Maximum reverse leakage current = 100nA

RATINGS AND CHARACTERISTIC CURVES

Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram



Note: 1. Rise Time = 7ns, max.
Input Impedance = 1megohm,22pF.
2. Ries Time =10ns, max.
Source Impedance = 50 ohms.

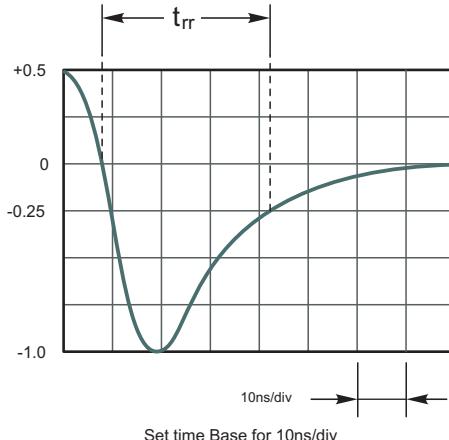


Fig.2 Maximum Average Forward Current Rating

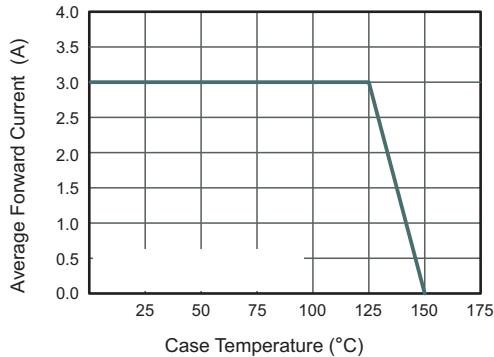


Fig.4 Typical Forward Characteristics

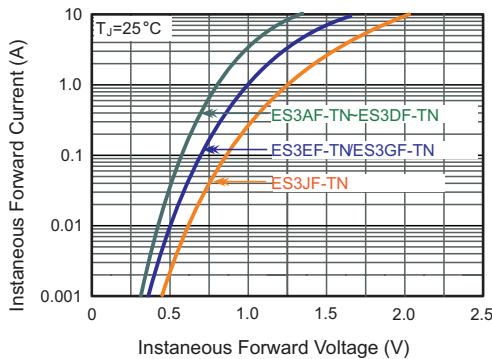


Fig.6 Maximum Non-Repetitive Peak Forward Surge Current

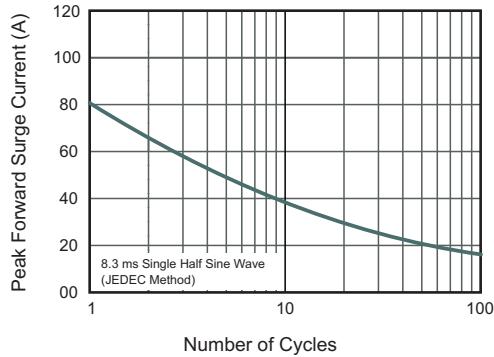


Fig.3 Typical Reverse Characteristics

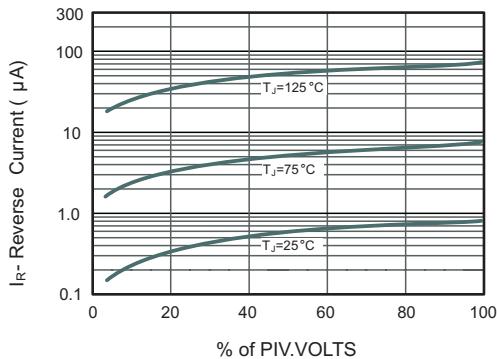
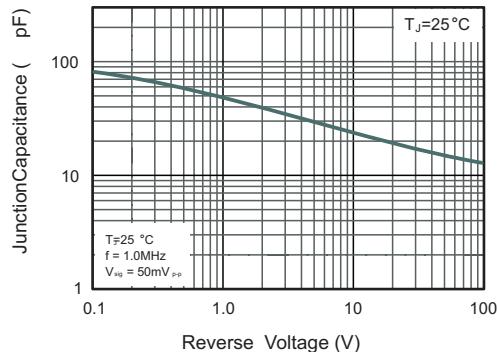
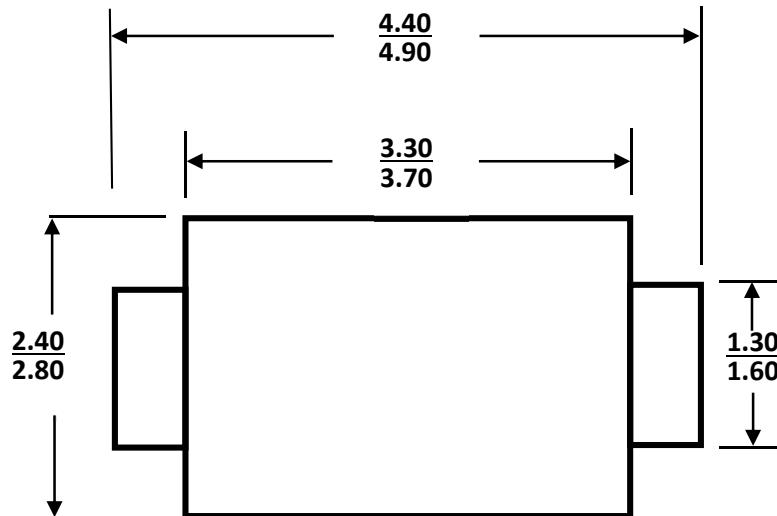


Fig.5 Typical Junction Capacitance



PACKAGE OUTLINE

SMAF



Dimensions in millimeters

ORDERING INFORMATION

Device	Package	Shipping
ES3AF-TN thru ES3JF-TN	SMAF	3,000/Tape & Reel (7 inches)
		10,000/ Tape & Reel (13 inches)